# **General Purpose Transistors**

**NPN Silicon** 

# **BC846ALT1G Series**

#### **Features**

- Moisture Sensitivity Level: 1
- ESD Rating Human Body Model: > 4000 V
  - Machine Model: > 400 V
- S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Collector-Emitter Voltage  BC846 BC847, BC850 BC848, BC849	V <sub>CEO</sub>	65 45 30	Vdc
Collector-Base Voltage  BC846  BC847, BC850  BC848, BC849	V <sub>CBO</sub>	80 50 30	Vdc
Emitter-Base Voltage  BC846  BC847, BC850  BC848, BC849	V <sub>EBO</sub>	6.0 6.0 5.0	Vdc
Collector Current – Continuous	I <sub>C</sub>	100	mAdc

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

#### THERMAL CHARACTERISTICS

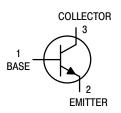
Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board, (Note 1)  T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	225	mW
Derate above 25°C		1.8	mW/°C
Thermal Resistance, Junction-to-Ambient (Note 1)	$R_{\theta JA}$	556	°C/W
Total Device Dissipation Alumina Substrate (Note 2) T <sub>A</sub> = 25°C	P <sub>D</sub>	300	mW
Derate above 25°C		2.4	mW/°C
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{ hetaJA}$	417	°C/W
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

- 1. FR-5 =  $1.0 \times 0.75 \times 0.062$  in.
- 2. Alumina =  $0.4 \times 0.3 \times 0.024$  in 99.5% alumina.



# ON Semiconductor®

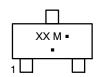
#### www.onsemi.com





SOT-23 CASE 318 STYLE 6

#### **MARKING DIAGRAM**



XX = Device Code
M = Date Code\*
• Pb-Free Package

(Note: Microdot may be in either location)

\*Date Code orientation and/or overbar may vary depending upon manufacturing location.

#### **ORDERING INFORMATION**

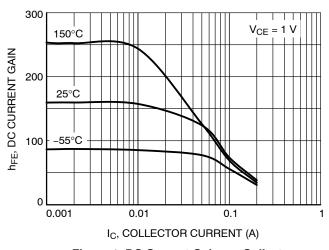
See detailed ordering and shipping information in the package dimensions section on page 12 of this data sheet.

# **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

Characteris	Symbol	Min	Тур	Max	Unit	
OFF CHARACTERISTICS						
Collector - Emitter Breakdown Voltage (I <sub>C</sub> = 10 mA)	BC846A, B, C BC847A, B, C, BC850B, C BC848A, B, C, BC849B, C	V <sub>(BR)CEO</sub>	65 45 30	- - -	- - -	V
Collector – Emitter Breakdown Voltage ( $I_C = 10 \mu A, V_{EB} = 0$ )	BC846A, B, C BC847A, B, C BC850B, C BC848A, B, C, BC849B, C	V <sub>(BR)</sub> CES	80 50 30	- - -	- - -	V
Collector – Base Breakdown Voltage ( $I_C = 10 \mu A$ )	•			- - -	- - -	V
Emitter – Base Breakdown Voltage ( $I_E = 1.0 \mu A$ )	BC846A, B, C BC847A, B, C, BC850B, C BC848A, B, C, BC849B, C	V <sub>(BR)EBO</sub>	6.0 6.0 5.0	- - -	- - -	V
Collector Cutoff Current (V <sub>CB</sub> = 30 V) (V <sub>CB</sub> = 30 V, T <sub>A</sub> = 150°C)	I <sub>CBO</sub>	- -	- -	15 5.0	nA μA	
ON CHARACTERISTICS						
DC Current Gain (I <sub>C</sub> = 10 $\mu$ A, V <sub>CE</sub> = 5.0 V)	BC846A, BC847A, BC848A BC846B, BC847B, BC848B BC846C, BC847C, BC848C	h <sub>FE</sub>	- - -	90 150 270	- - -	-
$(I_C = 2.0 \text{ mA}, V_{CE} = 5.0 \text{ V})$	BC846A, BC847A, BC848A BC846B, BC847B, BC848B, BC849B, BC850B		110 200	180 290	220 450	
BC846C, B0		420	520	800		
Collector – Emitter Saturation Voltage ( $I_C = (I_C = I_C)$	V <sub>CE(sat)</sub>	- -	- -	0.25 0.6	V	
Base – Emitter Saturation Voltage ( $I_C$ = 10 mA, $I_B$ = 0.5 mA) ( $I_C$ = 100 mA, $I_B$ = 5.0 mA)			- -	0.7 0.9	- -	V
Base – Emitter Voltage ( $I_C$ = 2.0 mA, $V_{CE}$ = ( $I_C$ = 10 mA, $V_{CE}$ = 5	V <sub>BE(on)</sub>	580 -	660 -	700 770	mV	
SMALL-SIGNAL CHARACTERISTICS						
Current – Gain – Bandwidth Product ( $I_C = 10$ mA, $V_{CE} = 5.0$ Vdc, $f = 100$ MHz)			100	_	-	MHz
Output Capacitance (V <sub>CB</sub> = 10 V, f = 1.0 MI	C <sub>obo</sub>	-	-	4.5	pF	
Noise Figure ( $I_C$ = 0.2 mA, $V_{CE}$ = 5.0 Vdc, $R_S$ = 2.0 k $\Omega$ , BC846 f = 1.0 kHz, BW = 200 Hz) BC849	NF	_ _	- -	10 4.0	dB	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

#### BC846A, BC847A, BC848A, SBC846A



300 150°C VCE = 5 V VCE = 5 V 200 25°C 100 -55°C 0 0.001 0.01 1C, COLLECTOR CURRENT (A)

Figure 1. DC Current Gain vs. Collector Current

Figure 2. DC Current Gain vs. Collector Current

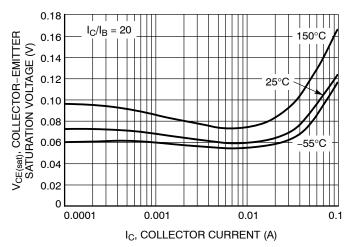


Figure 3. Collector Emitter Saturation Voltage vs. Collector Current

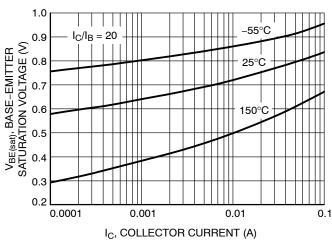


Figure 4. Base Emitter Saturation Voltage vs.
Collector Current

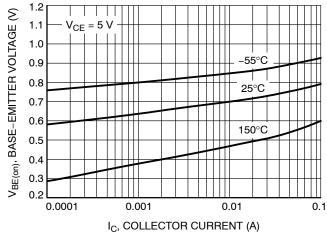
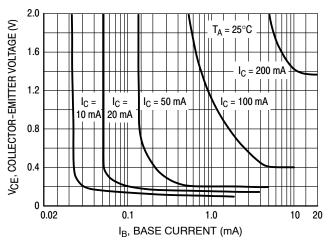


Figure 5. Base Emitter Voltage vs. Collector Current

# BC846A, BC847A, BC848A, SBC846A



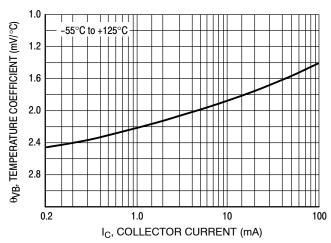


Figure 6. Collector Saturation Region

Figure 7. Base-Emitter Temperature Coefficient

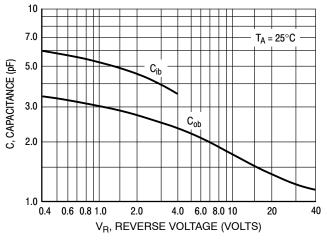


Figure 8. Capacitances

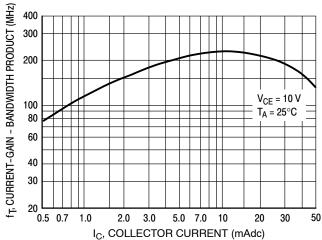


Figure 9. Current-Gain - Bandwidth Product

#### BC846B, SBC846B

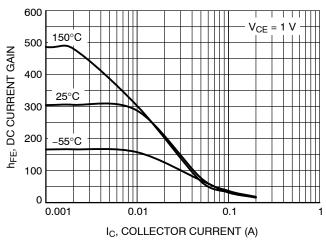


Figure 10. DC Current Gain vs. Collector Current

Figure 11. DC Current Gain vs. Collector Current

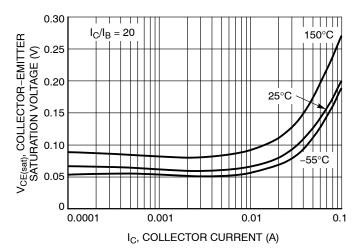


Figure 12. Collector Emitter Saturation Voltage vs. Collector Current

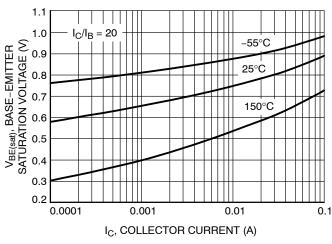


Figure 13. Base Emitter Saturation Voltage vs. Collector Current

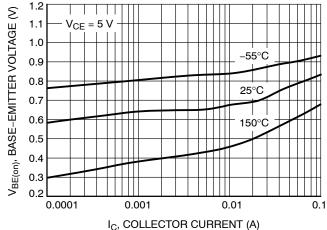
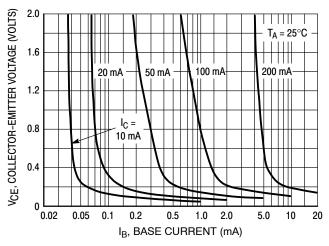


Figure 14. Base Emitter Voltage vs. Collector Current

# BC846B, SBC846B



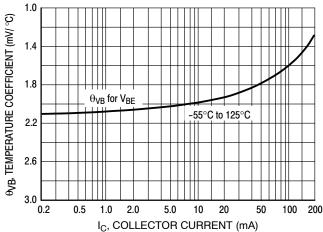


Figure 15. Collector Saturation Region

Figure 16. Base-Emitter Temperature Coefficient

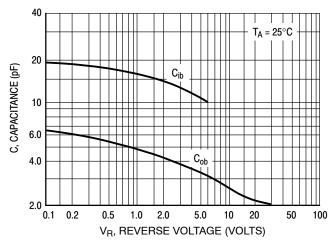


Figure 17. Capacitance

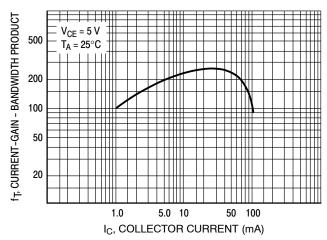
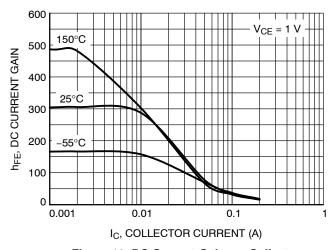


Figure 18. Current-Gain - Bandwidth Product

# BC847B, BC848B, BC849B, BC850B, SBC847B, SBC848B



600  $V_{CE} = 5 V$ 150°C 500 h<sub>FE</sub>, DC CURRENT GAIN 400 25°C 300 200 -55°C 100 0 0.001 0.01 0.1 I<sub>C</sub>, COLLECTOR CURRENT (A)

Figure 19. DC Current Gain vs. Collector Current

Figure 20. DC Current Gain vs. Collector Current

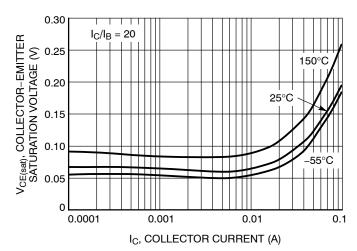


Figure 21. Collector Emitter Saturation Voltage vs. Collector Current

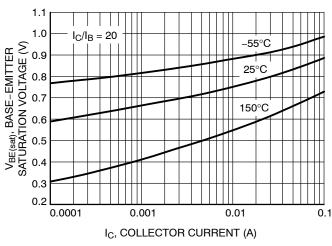


Figure 22. Base Emitter Saturation Voltage vs. Collector Current

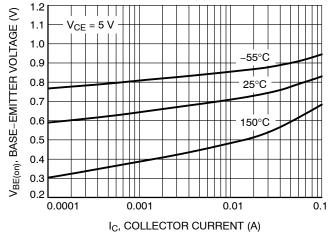
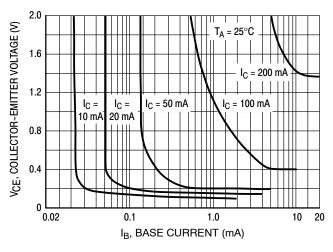


Figure 23. Base Emitter Voltage vs. Collector Current

# BC847B, BC848B, BC849B, BC850B, SBC846B, SBC847B, SBC848B



1.0 --55°C to +125°C 1.2 1.6 2.0 2.4 2.8 0.2 1.0 1.0 10 100 I<sub>C</sub>, COLLECTOR CURRENT (mA)

Figure 24. Collector Saturation Region

Figure 25. Base–Emitter Temperature Coefficient

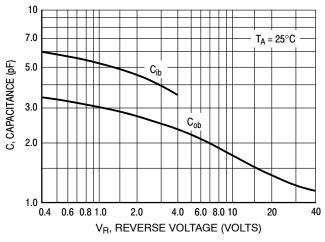


Figure 26. Capacitances

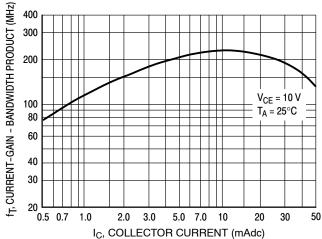
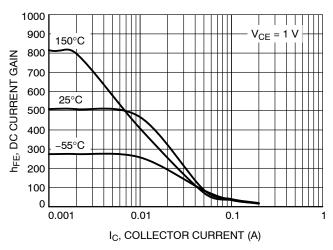


Figure 27. Current-Gain - Bandwidth Product

# BC846C, BC847C, BC848C, BC849C, BC850C, SBC847C



1000 900 150°C  $V_{CE}$ 800 hFE, DC CURRENT GAIN 700 600 25°C 500 400 -55°C 300 200 100 0.001 0.01 0.1 IC, COLLECTOR CURRENT (A)

Figure 28. DC Current Gain vs. Collector Current

Figure 29. DC Current Gain vs. Collector Current

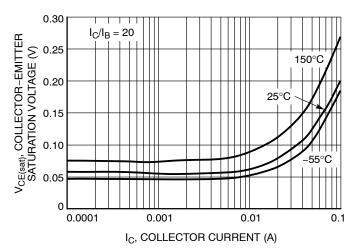


Figure 30. Collector Emitter Saturation Voltage vs. Collector Current

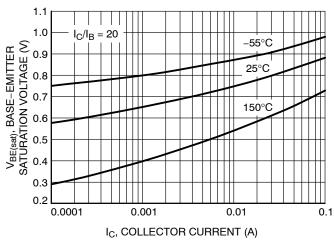


Figure 31. Base Emitter Saturation Voltage vs. Collector Current

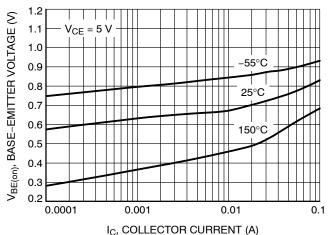
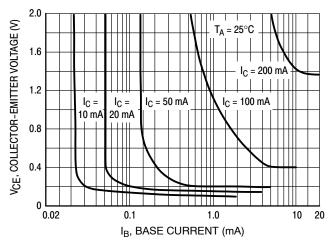


Figure 32. Base Emitter Voltage vs. Collector Current

# BC846C, BC847C, BC848C, BC849C, BC850C, SBC847C



1.0 --55°C to +125°C 1.2 1.6 2.0 2.4 2.8 0.2 1.0 1.0 10 100 100 100

Figure 33. Collector Saturation Region

Figure 34. Base–Emitter Temperature Coefficient

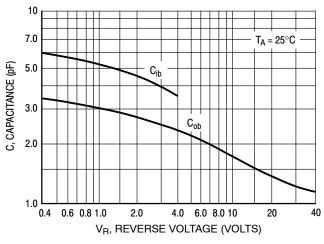


Figure 35. Capacitances

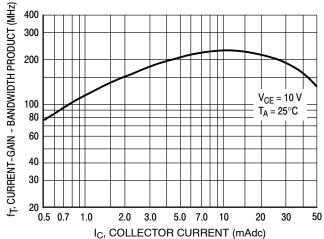


Figure 36. Current-Gain - Bandwidth Product

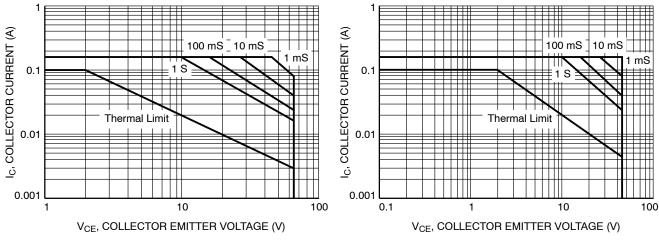


Figure 37. Safe Operating Area for BC846A, BC846B, BC846C

Figure 38. Safe Operating Area for BC847A, BC847B, BC847C, BC850B, BC850C

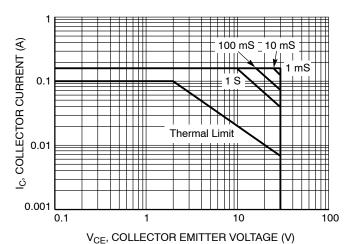


Figure 39. Safe Operating Area for BC848A, BC848B, BC848C, BC849B, BC849C

#### **ORDERING INFORMATION**

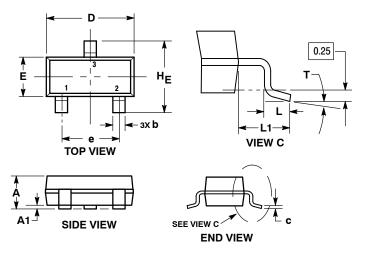
Device	Marking	Package	Shipping <sup>†</sup>		
BC846ALT1G			3,000 / Tape & Reel		
SBC846ALT1G*	1A				
BC846ALT3G			10,000 / Tape & Reel		
BC846BLT1G			0.000 (7		
SBC846BLT1G*			3,000 / Tape & Reel		
BC846BLT3G	1B		10 000 /T		
SBC846BLT3G*			10,000 / Tape & Reel		
BC846CLT1G	3C		3,000 / Tape & Reel		
BC847ALT1G			3,000 / Tape & Reel		
BC847ALT3G	1E		10,000 / Tape & Reel		
BC847BLT1G					
SBC847BLT1G*			3,000 / Tape & Reel		
BC847BLT3G	1F				
NSVBC847BLT3G*			10,000 / Tape & Reel		
BC847CLT1G		SOT-23 (Pb-Free)			
SBC847CLT1G*	1G		3,000 / Tape & Reel		
BC847CLT3G			10,000 / Tape & Reel		
BC848ALT1G	1J	(. 2	3,000 / Tape & Reel		
BC848BLT1G					
SBC848BLT1G*	1K		3,000 / Tape & Reel		
BC848BLT3G			10,000 / Tape & Reel		
BC848CLT1G			0.000 (T 0. P I		
NSVBC848CLT1G*	1L		3,000 / Tape & Reel		
BC848CLT3G			10,000 / Tape & Reel		
BC849BLT1G			0.000 / Table 9 Park		
NSVBC849BLT1G*	2B		3,000 / Tape & Reel		
BC849BLT3G			10,000 / Tape & Reel		
BC849CLT1G			3,000 / Tape & Reel		
BC849CLT3G	2C		10,000 / Tape & Reel		
BC850BLT1G	oF.				
NSVBC850BLT1G*	2F		2 000 / Terra 9 Daal		
BC850CLT1G	00	1	3,000 / Tape & Reel		
NSVBC850CLT1G*	2G				

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

<sup>\*</sup>S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.

#### PACKAGE DIMENSIONS

#### SOT-23 (TO-236) CASE 318-08 **ISSUE AS**



- NOTES:

  1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.

  2. CONTROLLING DIMENSION: MILLIMETERS.

  3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH.
  MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF
- THE BASE MATERIAL.
  DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

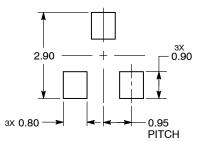
	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.89	1.00	1.11	0.035	0.039	0.044
A1	0.01	0.06	0.10	0.000	0.002	0.004
b	0.37	0.44	0.50	0.015	0.017	0.020
С	0.08	0.14	0.20	0.003	0.006	0.008
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
е	1.78	1.90	2.04	0.070	0.075	0.080
L	0.30	0.43	0.55	0.012	0.017	0.022
L1	0.35	0.54	0.69	0.014	0.021	0.027
HE	2.10	2.40	2.64	0.083	0.094	0.104
Т	0°		10°	0°		10°

STYLE 6:

BASE

- EMITTER
- COLLECTOR

#### RECOMMENDED SOLDERING FOOTPRINT\*



**DIMENSIONS: MILLIMETERS** 

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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Europe, Middle East and Africa Technical Support:

Phone: 00421 33 790 2910

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